



DRAM

3.3V SDR SDRAM

A complete offering from 16Mbit to 512Mbit

► ISSI SDR Standard Features:

- Single supply voltage of 3.3V ± 0.3V
- Standard SDRAM clock timing
- LVTTTL compatible inputs
- Four internal banks with bank controls^[2]
- Data masking per byte on Read or Write commands
- Programmable burst length of 1, 2, 4, 8, or full page
- Programmable CAS Latency of 2 or 3
- Auto-Refresh and Self-Refresh Modes
- Auto-Precharge Supported
- JEDEC compliant:
 - 54-ball BGA or 54-pin TSOP-II for x16^[2]
 - 90-ball BGA or 86-pin TSOP-II for x32

► Applications:

- Wireless Access Points
- Base Stations
- Routers
- Network Storage
- Energy Management
- Industrial Controls
- Car Infotainment
- Automotive Telematics

► 200MHz High Speed Option

- 1Mx16, 4Mx16, and 8Mx16 organizations
- Single Supply Voltage of 3.3V ± 0.3V
- CAS Latency of 3
- JEDEC compliant TSOP and BGA

Key Timing Parameters

Speed [Max Freq.]	-5	-6	-7	-75E	Units
CL = 3	200	166	143	-	MHz
CL = 2	100	100	100	133	MHz

Note: These are general specs. For any given part number, please refer to the corresponding datasheet for the timing specifications.

ISSI SDR Ordering Options

Density	Config.	Part Number ^[1,3]	Package		Temperature Grade		
			TSOP2	BGA	Com.	Ind.	Auto.
16Mbit	1M x 16	IS42S16100H	■	■	■	■	■
64Mbit	4M x 16	IS42S16400J	■	■	■	■	■
	2M x 32	IS42S32200L	■	■	■	■	■
128Mbit	16M x 8	IS42S81600F	■	■	■	■	■
	8M x 16	IS42S16800F	■	■	■	■	■
	4M x 32	IS42S32400F	■	■	■	■	■
256Mbit	32M x 8	IS42S83200G, IS42S83200J	■	■	■	■	■
	16M x 16	IS42S16160G, IS42S16160J	■	■	■	■	■
	8M x 32	IS42S32800G, IS42S32800J	■	■	■	■	■
512Mbit	64M x 8	IS42S86400D, IS42S86400F	■	■	■	■	■
	32M x 16	IS42S16320D, IS42S16320F	■	■	■	■	■
	16M x 32	IS42S32160D, IS42S32160F	■	■	■	■	■

Notes:

1. Automotive grade SDR part numbers begin with "IS45S".

2. 16Mbit has two internal banks and JEDEC packaging is different.